Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type $(\pi - MOSVII)$

TK15J50D

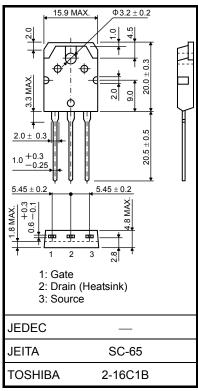
Switching Regulator Applications

• Low drain-source ON resistance: RDS (ON) = 0.33Ω (typ.)

- High forward transfer admittance: $|Y_{fs}| = 8.0 \text{ S (typ.)}$
- Low leakage current: $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 500 \text{ V)}$
- Enhancement-mode: $V_{th} = 2.0 \text{ to } 4.0 \text{ V (V}_{DS} = 10 \text{ V, I}_{D} = 1 \text{ mA)}$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	500	V
Gate-source voltage		V_{GSS}	±30	V
Drain current	DC (Note 1)	I _D	15	Α
	Pulse (Note 1)	I _{DP}	60	A
Drain power dissipati	on (Tc = 25°C)	P _D	210	W
Single pulse avalanche energy (Note 2)		E _{AS}	360	mJ
Avalanche current		I _{AR}	15	Α
Repetitive avalanche energy (Note 3)		E _{AR}	21	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55 to 150	°C



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	0.595	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	50	°C/W

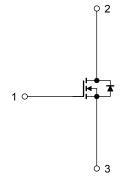
Note 1: Please use devices on conditions that the channel temperature is below 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 2.72 mH, R_G = 25 Ω , I_{AR} = 15 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic sensitive device. Please handle with caution.





Start of commercial production 2009-01

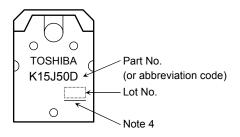
Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μΑ
Drain cut-off current		I _{DSS}	V _{DS} = 500 V, V _{GS} = 0 V	_	_	10	μА
Drain-source brea	akdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	500	_	_	V
Gate threshold vo	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	_	4.0	V
Drain-source ON	resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 7.5 A	_	0.33	0.4	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 7.5 A	2.0	8.0	_	S
Input capacitance		C _{iss}		_	1800	_	
Reverse transfer capacitance		C _{rss}	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	9	_	pF
Output capacitance		Coss		_	190	_	
Switching time	Rise time	t _r	V_{GS} V_{OD} $V_{DD} \approx 200 \text{ V}$	_	40	_	
	Turn-on time	t _{on}			80	_	ns
	Fall time	t _f			15	_	110
	Turn-off time	t _{off}	Duty ≤ 1%, t _W = 10 μs		110	_	
Total gate charge		Qg			38		
Gate-source charge		Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$	_	24	_	nC
Gate-drain charge		Q _{gd}		_	14	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

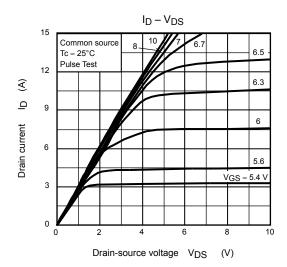
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	15	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	60	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 15 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 15 \text{ A}, V_{GS} = 0 \text{ V},$	_	1200	_	ns
Reverse recovery charge	Q _{rr}	dI _{DR} /dt = 100 A/μs	_	13	_	μС

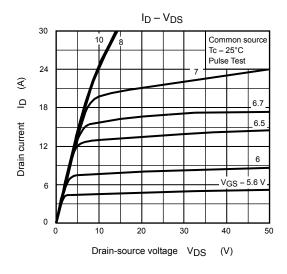
Marking

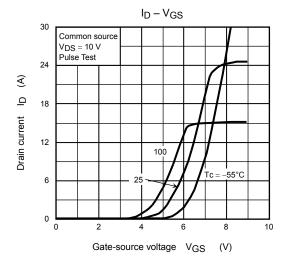


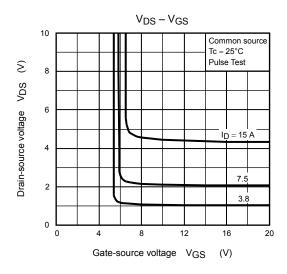
Note 4: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

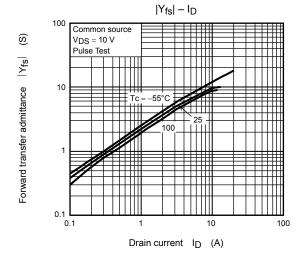
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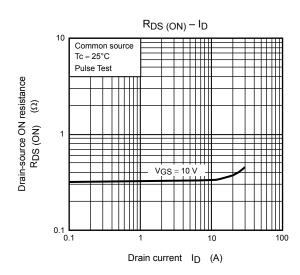


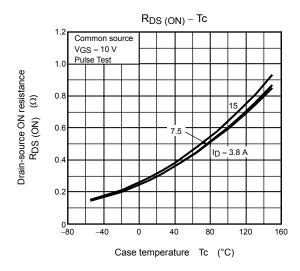


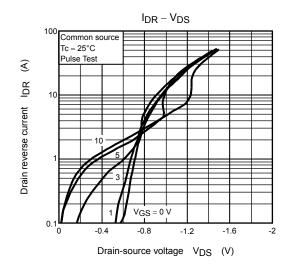


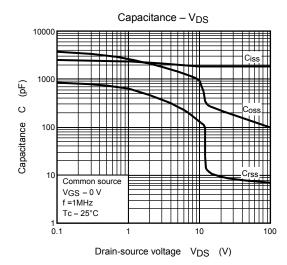


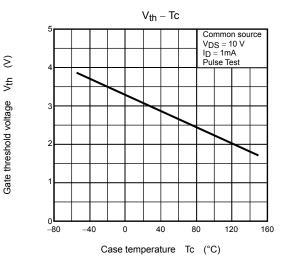


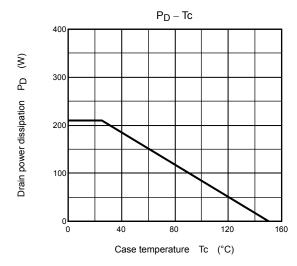


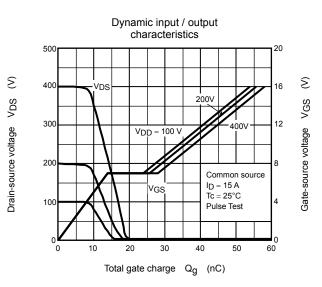


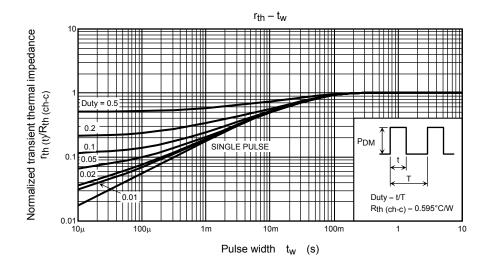


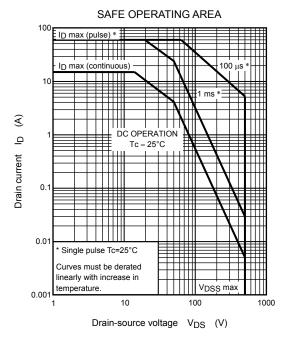


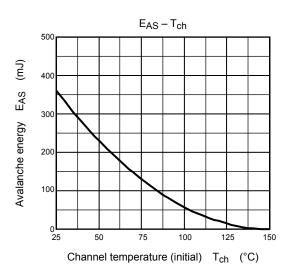


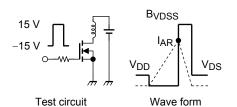












$$R_G = 25 \Omega$$

 $V_{DD} = 90 \text{ V}, L = 2.72 \text{ mH}$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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